



# PQMD12

NPN/PNP resistor-equipped transistors;  
R1 = 47 k $\Omega$ , R2 = 47 k $\Omega$

8 July 2015

Product data sheet

## 1. General description

NPN/PNP double Resistor-Equipped Transistors (RET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Low package height of 0.37 mm
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

## 3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications
- Mobile applications

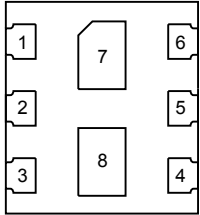
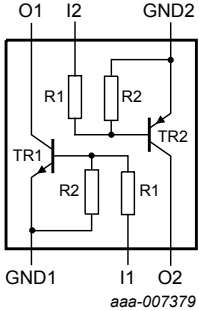
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor; for the PNP transistor with negative polarity</b>						
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	50	V
I <sub>O</sub>	output current		-	-	100	mA
<b>Per transistor; for the PNP transistor with negative polarity</b>						
R1	resistance 1	T <sub>amb</sub> = 25 °C	33	47	61	k $\Omega$
R2/R1	resistance ratio		0.8	1	1.2	

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 <p>Transparent top view <b>DFN1010B-6 (SOT1216)</b></p>	 <p>aaa-007379</p>
2	I1	input ( base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input ( base) TR2		
6	O1	output (collector) TR1		
7	O1	output (collector) TR1		
8	O2	output (collector) TR2		

## 6. Ordering information

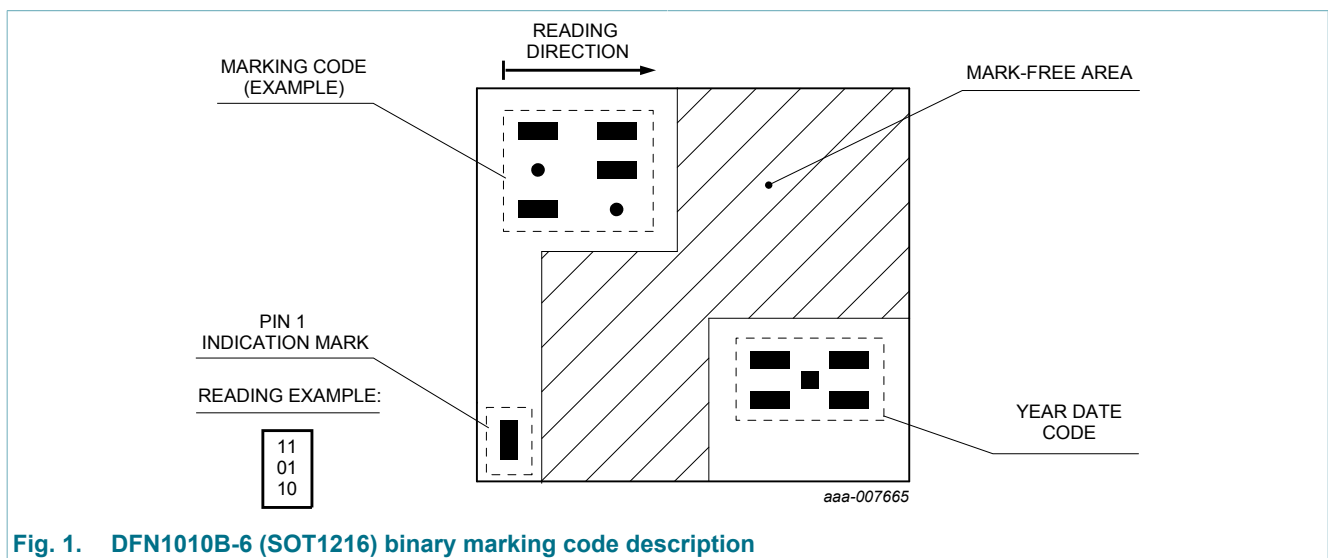
Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PQMD12	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PQMD12	11 00 00



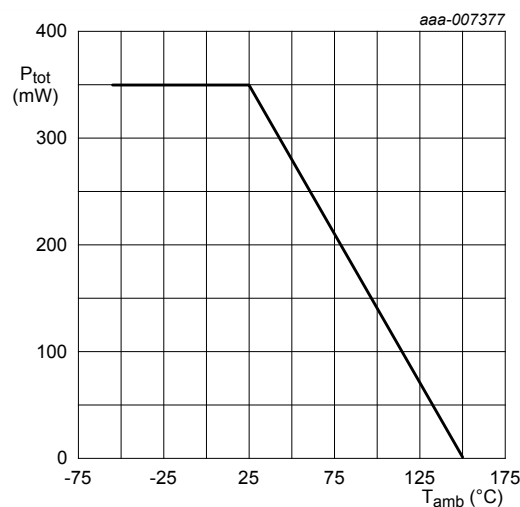
## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
<b>Per transistor; for the PNP transistor with negative polarity</b>						
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	10	V
V <sub>I</sub>	input voltage	TR1; positive		-	40	V
		TR1; negative		-	-10	V
		TR2; positive		-	10	V
		TR2; negative		-	-40	V
I <sub>O</sub>	output current			-	100	mA
I <sub>CM</sub>	peak collector current	t <sub>p</sub> ≤ 1 ms; single pulse;		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	230	mW
<b>Per device</b>						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	350	mW
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



FR4 PCB, standard footprint

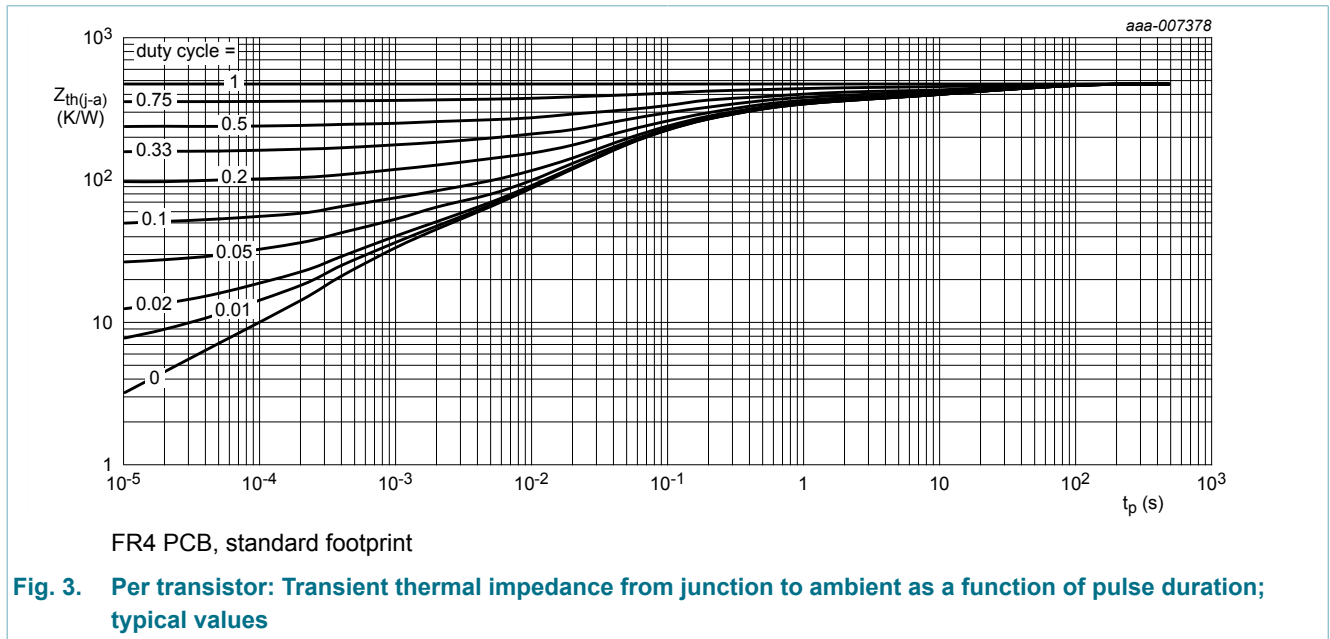
**Fig. 2. Per device: Power derating curve**

## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Per transistor</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
<b>Per device</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

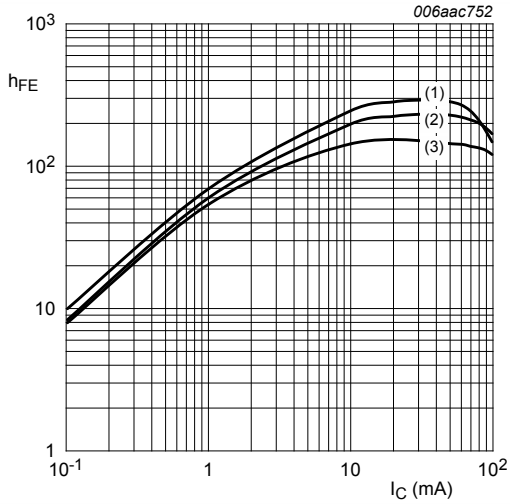


## 10. Characteristics

Table 7. Characteristics

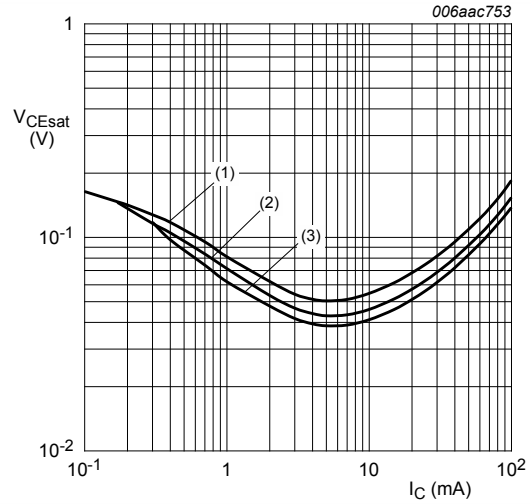
Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>Per transistor; for the PNP transistor with negative polarity</b>							
$I_{CBO}$	collector-base cut-off current (emitter open)	$V_{CB} = 50\text{ V}$ ; $I_E = 0\text{ A}$ ; $T_{amb} = 25\text{ °C}$	-	-	100	nA	
$I_{CEO}$	collector-emitter cut-off current (base open)	$V_{CE} = 30\text{ V}$ ; $I_B = 0\text{ A}$ ; $T_{amb} = 25\text{ °C}$	-	-	1	μA	
		$V_{CE} = 30\text{ V}$ ; $I_B = 0\text{ A}$ ; $T_{amb} = 150\text{ °C}$	-	-	5	μA	
$I_{EBO}$	emitter-base cut-off current (collector open)	$V_{EB} = 5\text{ V}$ ; $I_C = 0\text{ A}$ ; $T_{amb} = 25\text{ °C}$	-	-	90	μA	
$h_{FE}$	DC current gain	$V_{CE} = 5\text{ V}$ ; $I_C = 5\text{ mA}$ ; $T_{amb} = 25\text{ °C}$	80	-	-		
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 10\text{ mA}$ ; $I_B = 0.5\text{ mA}$ ; $T_{amb} = 25\text{ °C}$	-	-	150	mV	
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5\text{ V}$ ; $I_C = 100\text{ μA}$ ; $T_{amb} = 25\text{ °C}$	-	1.2	0.8	V	
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3\text{ V}$ ; $I_C = 2\text{ mA}$ ; $T_{amb} = 25\text{ °C}$	3	1.6	-	V	
R1	resistance 1	$T_{amb} = 25\text{ °C}$	33	47	61	kΩ	
R2/R1	resistance ratio		0.8	1	1.2		
$C_C$	collector capacitance	$V_{CB} = 10\text{ V}$ ; $I_E = 0\text{ A}$ ; $f = 1\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$ ; TR1 (NPN)	-	-	2.5	pF	
		$V_{CB} = -10\text{ V}$ ; $I_E = 0\text{ A}$ ; $f = 1\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$ ; TR2 (PNP)	-	-	3	pF	
$f_T$	transition frequency	$V_{CE} = 5\text{ V}$ ; $I_C = 10\text{ mA}$ ; $f = 100\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$ ; TR1 (NPN)	[1]	-	230	-	MHz
		$V_{CE} = -5\text{ V}$ ; $I_C = -10\text{ mA}$ ; $f = 100\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$ ; TR2 (PNP)	[1]	-	180	-	MHz

[1] Characteristics of built-in transistor



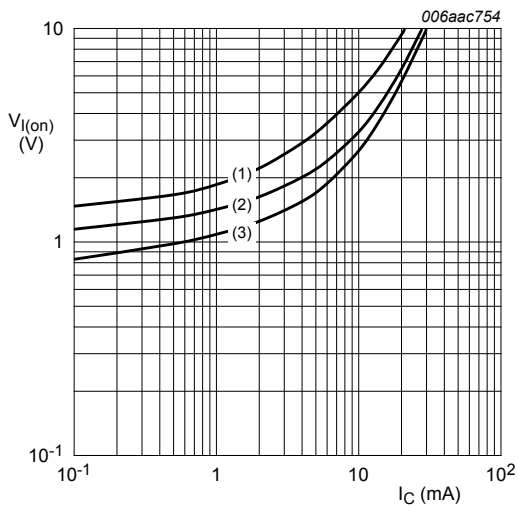
$V_{CE} = 5\text{ V}$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -40\text{ °C}$

**Fig. 4. NPN transistor: DC current gain as a function of collector current; typical values**



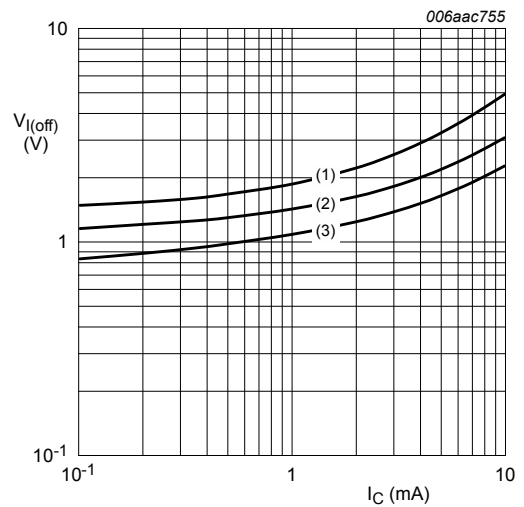
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -40\text{ °C}$

**Fig. 5. NPN transistor: Collector-emitter saturation voltage as a function of collector current; typical values**



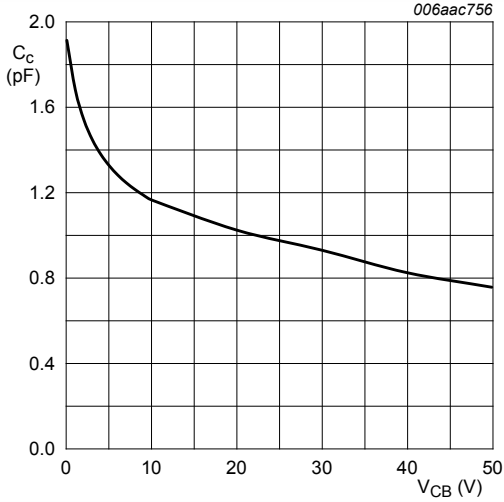
$V_{CE} = 0.3\text{ V}$   
 (1)  $T_{amb} = -40\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = 100\text{ °C}$

**Fig. 6. NPN transistor: On-state input voltage as a function of collector current; typical values**



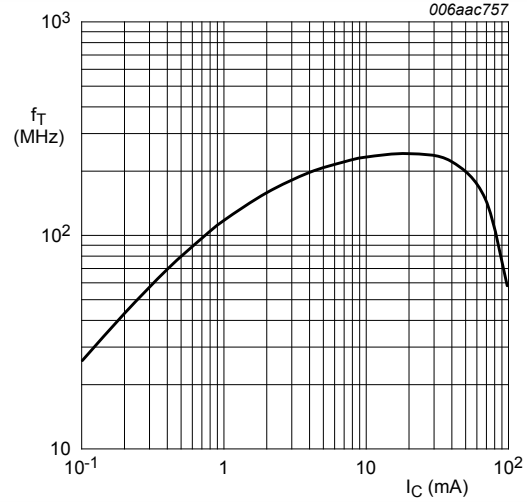
$V_{CE} = 5\text{ V}$   
 (1)  $T_{amb} = -40\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = 100\text{ °C}$

**Fig. 7. NPN transistor: Off-state input voltage as a function of collector current; typical values**



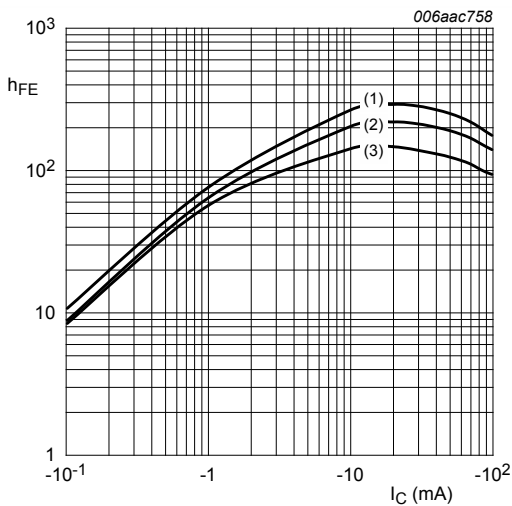
$f = 1 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$

**Fig. 8. NPN transistor: Collector capacitance as a function of collector-base voltage; typical values**



$V_{\text{CE}} = 5 \text{ V}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$

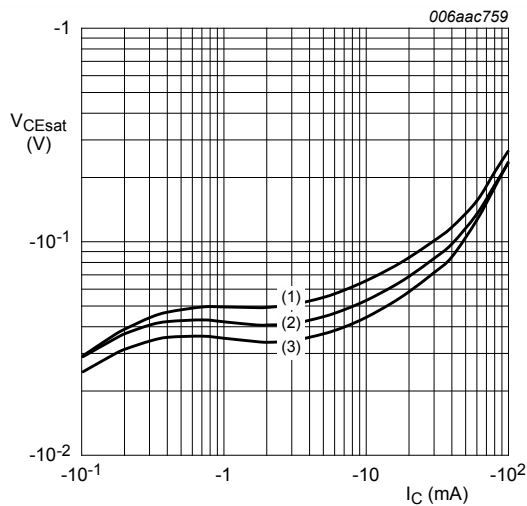
**Fig. 9. NPN transistor: Transition frequency as a function of collector current; typical values of built-in transistor**



$V_{\text{CE}} = -5 \text{ V}$

- (1)  $T_{\text{amb}} = 100 \text{ }^\circ\text{C}$
- (2)  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$
- (3)  $T_{\text{amb}} = -40 \text{ }^\circ\text{C}$

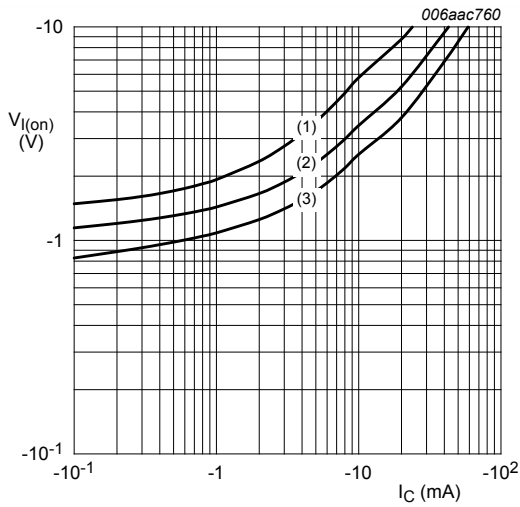
**Fig. 10. PNP transistor: DC current gain as a function of collector current; typical values**



$I_{\text{C}}/I_{\text{B}} = 20$

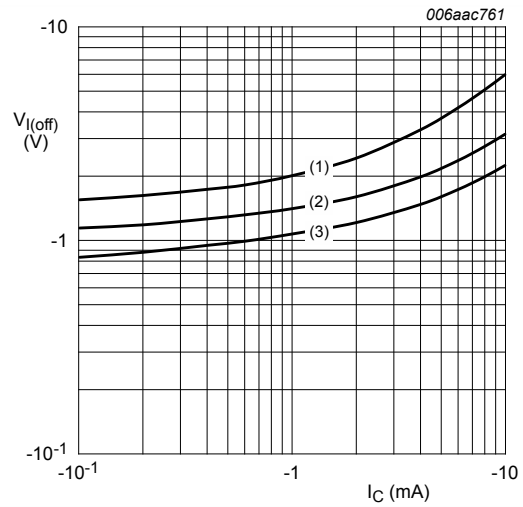
- (1)  $T_{\text{amb}} = 100 \text{ }^\circ\text{C}$
- (2)  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$
- (3)  $T_{\text{amb}} = -40 \text{ }^\circ\text{C}$

**Fig. 11. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values**



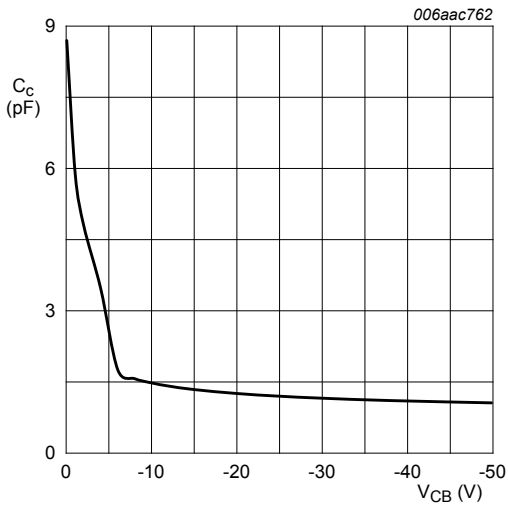
$V_{CE} = -0.3 \text{ V}$   
 (1)  $T_{amb} = -40 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

**Fig. 12. PNP transistor: On-state input voltage as a function of collector current; typical values**



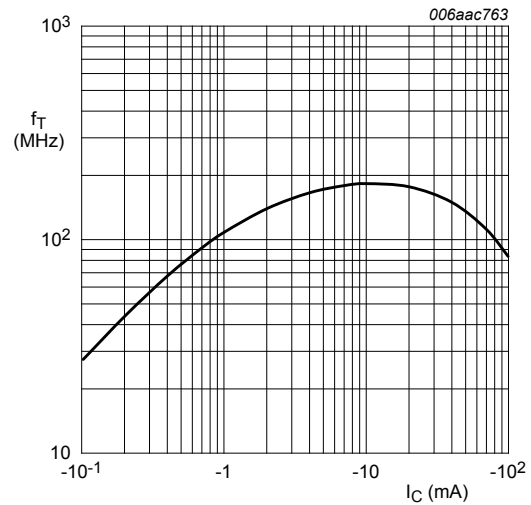
$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = -40 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

**Fig. 13. PNP transistor: Off-state input voltage as a function of collector current; typical values**



$f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^\circ\text{C}$

**Fig. 14. PNP transistor: Collector capacitance as a function of collector-base voltage; typical values of built-in transistor**



**Fig. 15. PNP transistor: Transition frequency as a function of collector current; typical values of built-in transistor**

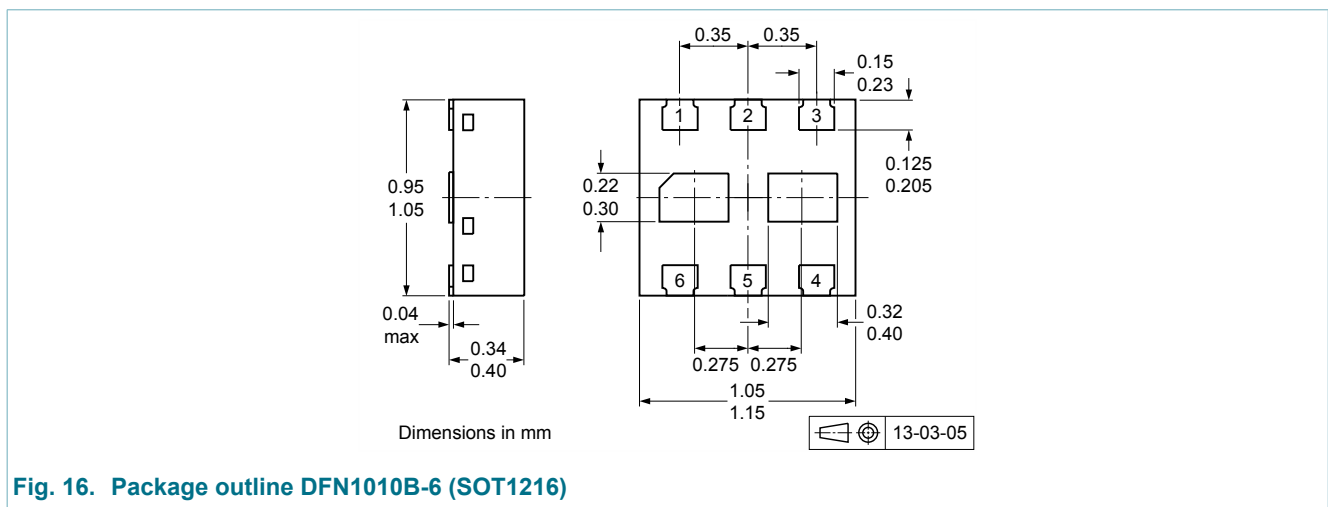


## 11. Test information

### 11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

## 12. Package outline



### 13. Soldering

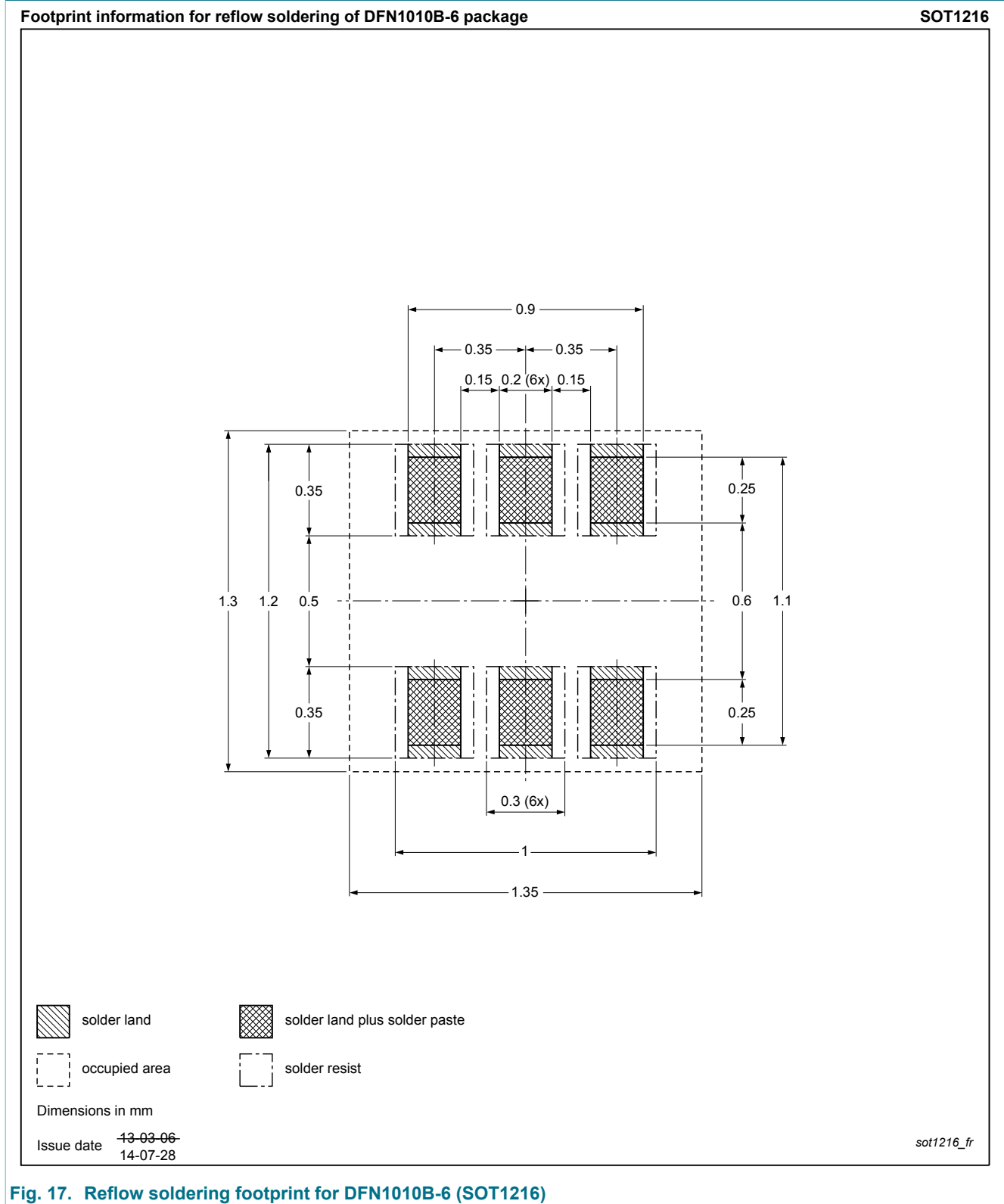


Fig. 17. Reflow soldering footprint for DFN1010B-6 (SOT1216)

## 14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PQMD12 v.2	20150708	Product data sheet	-	PQMD12 v.1
Modification:	<ul style="list-style-type: none"><li>Change of binary marking code position.</li></ul>			
PQMD12 v.1	20130724	Product data sheet	-	-

## 15. Legal information

### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 08 July 2015